# HIGH POWER SP4T SWITCH GaAs MMIC

1.35 to 5.0V

+32dBm min.

250ns typ.

## ■ GENERAL DESCRIPTION

The NJG1809ME7 is a high power SP4T switch MMIC suitable for LTE-U / LAA, WLAN, and LTE applications.

This switch features very low insertion loss and high isolation up to 6GHz and excellent linearity performance with 1.8V control voltage.

This switch achieves high speed switching time for WLAN application. Integrated ESD protection device on each port achieves excellent ESD robustness. No DC Blocking capacitors are required for all RF ports unless DC is biased externally.

The small and thin EQFN18-E7 package is adopted.

## ■ APPLICATIONS

LTE-U / LAA, WLAN (802.11a/b/g/n/ac), LTE multi-mode applications General purpose switching applications

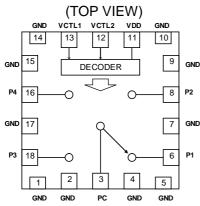
## ■ FEATURES

- Low voltage logic control
- Low insertion loss
- High isolation

• P-0.1dB

- High speed switching time
- Small and thin package
- RoHS compliant and Halogen Free, MSL1

#### ■ PIN CONFIGURATION



Pin connectior	า
1. GND	10. GND
2. GND	11. VDD
3. PC	12. VCTL2
4. GND	13. VCTL1
5. GND	14. GND
6. P1	15. GND
7. GND	16. P4
8. P2	17. GND
9. GND	18. P3
Exposed PAD:	GND

0.40dB typ. @f=2.7GHz, 3.5GHz, P<sub>IN</sub>=+27dBm

0.50dB typ. @f=5.85GHz, P<sub>IN</sub>=+27dBm

27dB typ. @f=2.7GHz,  $P_{IN}$ =+27dBm 25dB typ. @f=3.5GHz,  $P_{IN}$ =+27dBm 30dB typ. @f=5.85GHz,  $P_{IN}$ =+27dBm

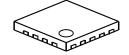
EQFN18-E7 (2.0x2.0x0.397mm typ.)

## ■ TRUTH TABLE

"H"= $V_{CTL(H)}$ , "L"= $V_{CTL(L)}$				
VCTL1	VCTL2	Path		
L	L	PC-P1		
Н	L	PC-P2		
L	Н	PC-P3		
Н	Н	PC-P4		

NOTE: Please note that any information on this datasheet will be subject to change.

## PACKAGE OUTLINE



NJG1809ME7

## ■ ABSOLUTE MAXIMUM RATINGS

 $(T_a = +25^{\circ}C, Z_s = Z_l = 50\Omega)$ 

			(·a ·=; -s	
PARAMETER	SYMBOL	CONDITIONS	RATINGS	UNITS
RF Input Power	P <sub>IN</sub>	V <sub>DD</sub> =2.75V, V <sub>CTL</sub> =0/1.8V	+33	dBm
Supply Voltage	$V_{DD}$	VDD terminal	5.0	V
Control Voltage	V <sub>CTL</sub>	VCTL1, VCTL2 terminal	5.0	V
Power Dissipation	P <sub>D</sub>	Four-layer FR4 PCB with through-hole (101.5x114.5mm), T <sub>j</sub> =150°C	1400	mW
Operating Temp.	T <sub>opr</sub>		-40 to +105	°C
Storage Temp.	T <sub>stg</sub>		-55 to +150	°C

## ■ ELECTRICAL CHARACTERISTICS 1 (DC)

(General conditions:  $T_a$ =+25°C,  $V_{DD}$ =2.75V,  $V_{CTL(H)}$ =1.8V,  $V_{CTL(L)}$ =0V, with application circuit)

PARAMETERS	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Supply Voltage	$V_{DD}$	VDD Terminal	2.5	2.75	5.0	V
Operating Current	I <sub>DD</sub>	No RF input	-	350	700	μA
Control Voltage (LOW)	V <sub>CTL(L)</sub>	VCTL1, VCTL2 Terminal	0	-	0.45	V
Control Voltage (HIGH)	V <sub>CTL(H)</sub>	VCTL1, VCTL2 Terminal	1.35	1.8	5.0	V
Control Current	I <sub>CTL</sub>	V <sub>CTL(H)</sub> =1.8V	-	4	10	μA

## ■ ELECTRICAL CHARACTERISTICS 2 (RF)

(General conditions:  $T_a$ =+25°C,  $Z_s$ = $Z_I$ =50 $\Omega$ ,  $V_{DD}$ =2.75V,  $V_{CTL(H)}$ =1.8V,  $V_{CTL(L)}$ =0V, with application circuit)

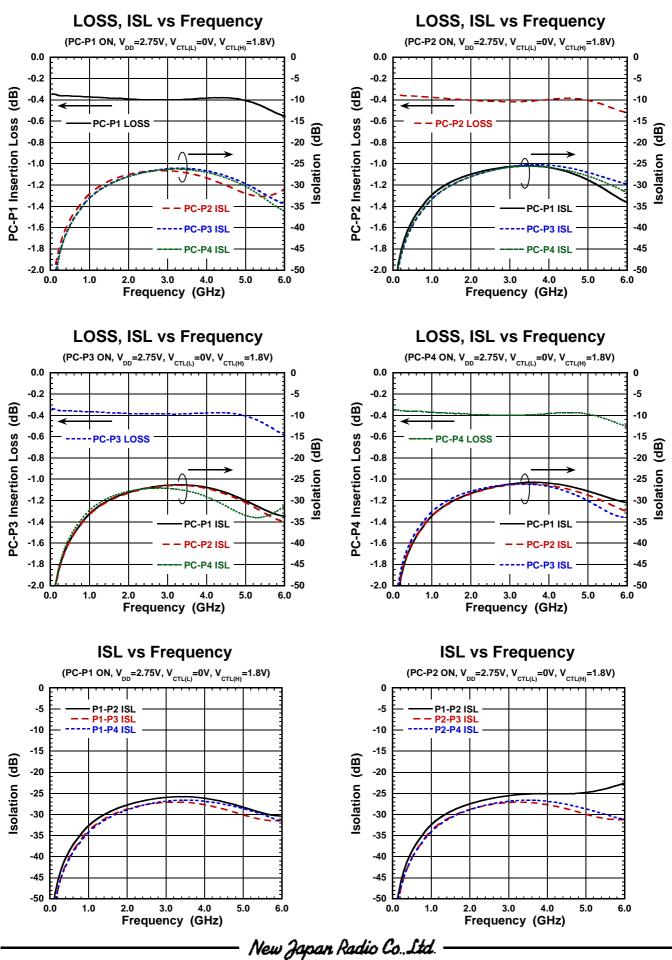
PARAMETERS	SYMBOL	$\frac{5 \text{ C},  \text{C}_{\text{S}} = \text{Z}_{\text{I}} = 50 \text{ S}2,  \text{V}_{\text{DD}} = 2.75 \text{ V},  \text{V}_{\text{CTL}(\text{H})} = 1.8 \text{ V},  \text{V}_{\text{C}}}{\text{CONDITIONS}}$		MIN	TYP	MAX	UNITS
Insertion Loss 1	LOSS1	f=0.7GHz, P <sub>IN</sub> =+27dBm		-	0.35	0.55	dB
Insertion Loss 2	LOSS2	f=2.0GHz, P <sub>IN</sub> =+27dBm		-	0.40	0.60	dB
Insertion Loss 3	LOSS3	f=2.7GHz, P <sub>IN</sub> =+27dBm		-	0.40	0.60	dB
Insertion Loss 4	LOSS4	f=3.5GHz, P <sub>IN</sub> =+27dBm		-	0.40	0.60	dB
Insertion Loss 5	LOSS5	f=5.85GHz, P <sub>IN</sub> =+27dBm		-	0.50	0.75	dB
Isolation 1	ISL1	f=0.7GHz, P <sub>IN</sub> =+27dBm		32	36	-	dB
Isolation 2	ISL2	f=2.0GHz, P <sub>IN</sub> =+27dBm		25	28	-	dB
Isolation 3	ISL3	f=2.7GHz, P <sub>IN</sub> =+27dBm		24	27	-	dB
Isolation 4	ISL4	f=3.5GHz, P <sub>IN</sub> =+27dBm		22	25	-	dB
Isolation 5	ISL5	PC		26	30	-	
	1313	f=5.85GHz, P <sub>IN</sub> =+27dBm	Pm-Pn <sup>*2</sup>	20	23	-	dB
Input Power at 0.1 dB Compression Point	P <sub>-0.1dB</sub>	f=5.85GHz		+32	-	-	dBm
2nd Harmonics 1	2fo(1)	f=5.18GHz, 5.85GHz, P <sub>IN</sub> =+27dBm		-	-	-70	dBc
2nd Harmonics 2	2fo(2)	f=2.69GHz, P <sub>IN</sub> =0dBm		-	-	-95	dBc
3rd Harmonics 1	3fo(1)	f=5.18GHz, 5.85GHz, P <sub>IN</sub> =+27dBm		-	-	-70	dBc
3rd Harmonics 2	3fo(2)	f=1.732GHz, 1.91GHz, P <sub>IN</sub> =0dBm		-	-	-95	dBc
4th Harmonics	4fo	f=5.18GHz, 5.85GHz, P <sub>IN</sub> =+27dBm	f=5.18GHz, 5.85GHz,		-	-70	dBc
Input 2 <sup>nd</sup> order intercept point	IIP2	f=2.48+2.69GHz, f <sub>meas</sub> =5.17GHz, P <sub>IN</sub> =+10dBm each		+100	-	-	dBm
Input 3 <sup>rd</sup> order intercept point	IIP3	f=1.71+2.40GHz, f <sub>meas</sub> =5.82 GHz, P <sub>IN</sub> =+10dBm each		+60	-	-	dBm
VSWR1	VSWR1	On-state ports, f=2.7GHz		-	1.2	1.5	-
VSWR2	VSWR2	On-state ports, f=5.85GHz		-	1.3	1.6	-
Switching time	T <sub>sw</sub>	50% V <sub>CTL</sub> to 10/90% RF		-	250	400	ns

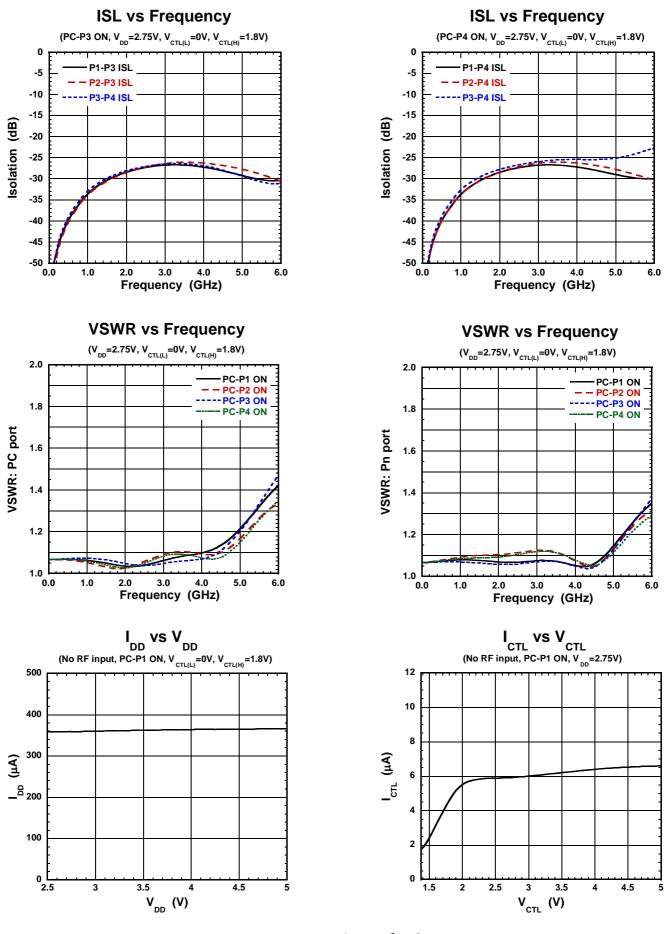
\*1: Pn=P1, P2, P3, P4

\*2: Pm=P1, P2, P3, P4. Pn=P1, P2, P3, P4. m≠n

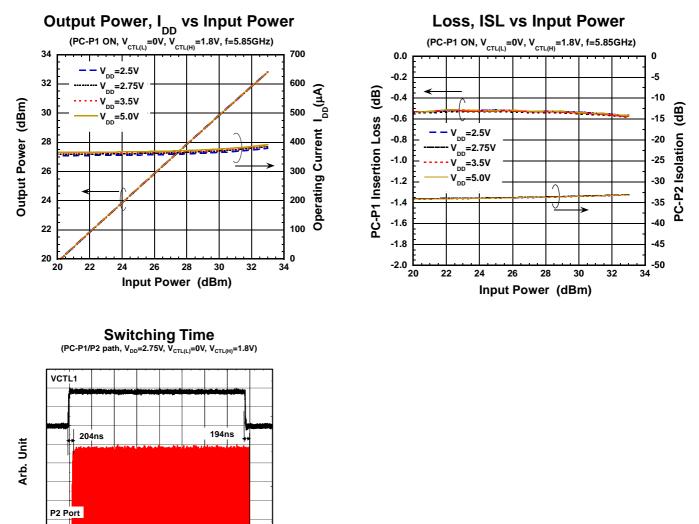
#### ■ TERMINAL INFORMATION

	INFORMATION	
No.	SYMBOL	DESCRIPTION
1	GND	Ground terminal. Please connect this terminal with ground plane as close as possible for excellent RF performance.
2	GND	Ground terminal. Please connect this terminal with ground plane as close as possible for excellent RF performance.
3	PC	Common RF terminal. No DC blocking capacitor is required for this port unless DC is biased externally.
4	GND	Ground terminal. Please connect this terminal with ground plane as close as possible for excellent RF performance.
5	GND	Ground terminal. Please connect this terminal with ground plane as close as possible for excellent RF performance.
6	P1	RF terminal. No DC blocking capacitor is required for this port unless DC is biased externally.
7	GND	Ground terminal. Please connect this terminal with ground plane as close as possible for excellent RF performance.
8	P2	RF terminal. No DC blocking capacitor is required for this port unless DC is biased externally.
9	GND	Ground terminal. Please connect this terminal with ground plane as close as possible for excellent RF performance.
10	GND	Ground terminal. Please connect this terminal with ground plane as close as possible for excellent RF performance.
11	VDD	Positive voltage supply terminal. The positive voltage (+2.5 to +5V) has to be supplied. Please connect a bypass capacitor with ground plane for excellent RF performance.
12	VCTL2	Control signal input terminal. This terminal is set to High-Level (+1.35 to +5.0V) or Low-Level (0 to +0.45V).
13	VCTL1	Control signal input terminal. This terminal is set to High-Level (+1.35 to +5.0V) or Low-Level (0 to +0.45V).
14	GND	Ground terminal. Please connect this terminal with ground plane as close as possible for excellent RF performance.
15	GND	Ground terminal. Please connect this terminal with ground plane as close as possible for excellent RF performance.
16	P4	RF terminal. No DC blocking capacitor is required for this port unless DC is biased externally.
17	GND	Ground terminal. Please connect this terminal with ground plane as close as possible for excellent RF performance.
18	P3	RF terminal. No DC blocking capacitor is required for this port unless DC is biased externally.
Exposed Pad	GND	Ground pad of IC bottom side. Please connect this pad with ground plane as close as possible for excellent RF performance.



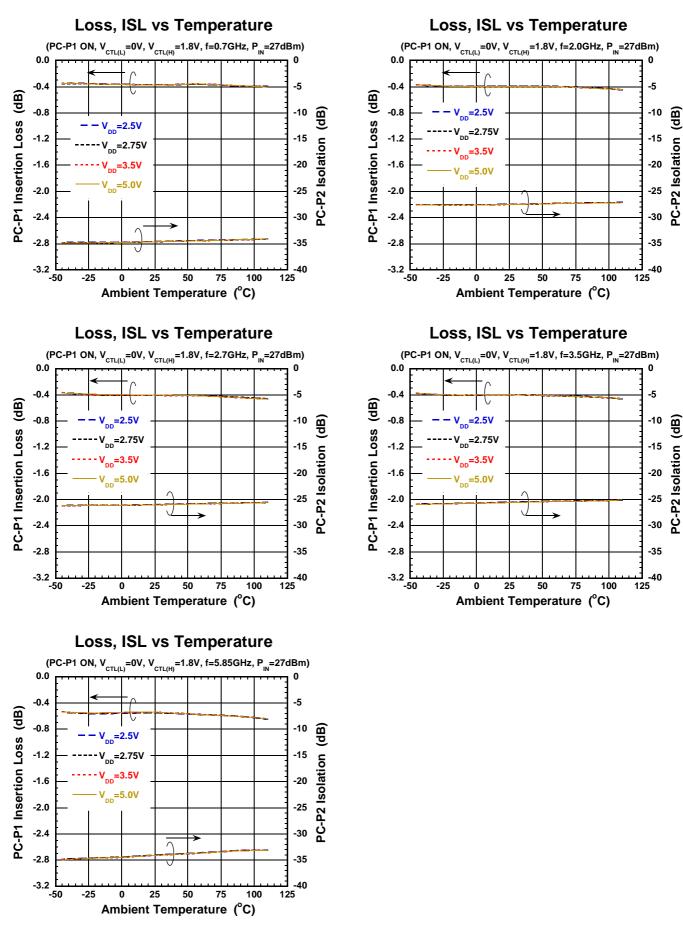


New Japan Radio Co., Ltd.

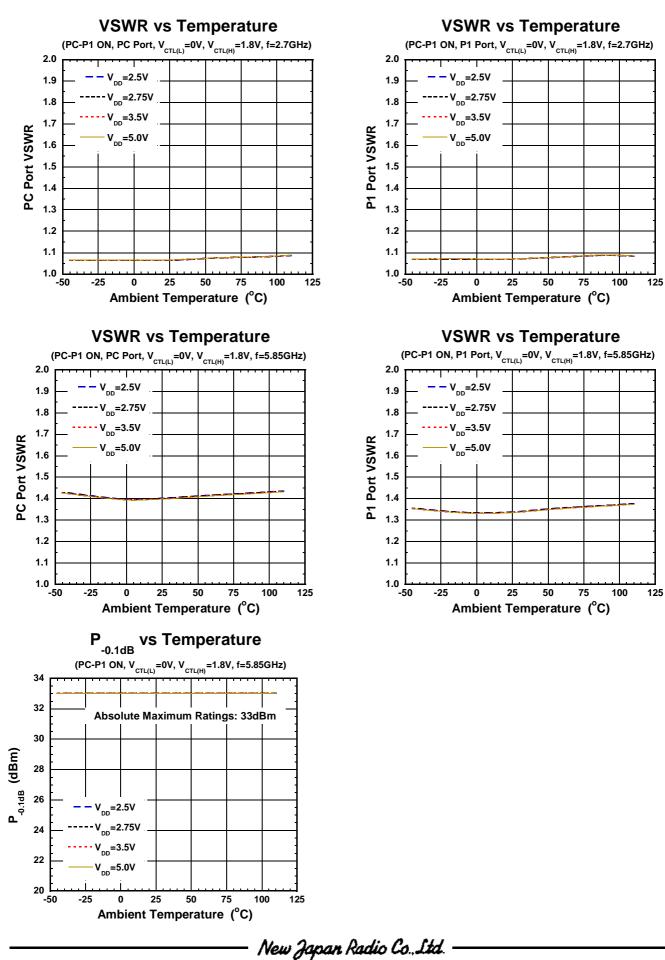


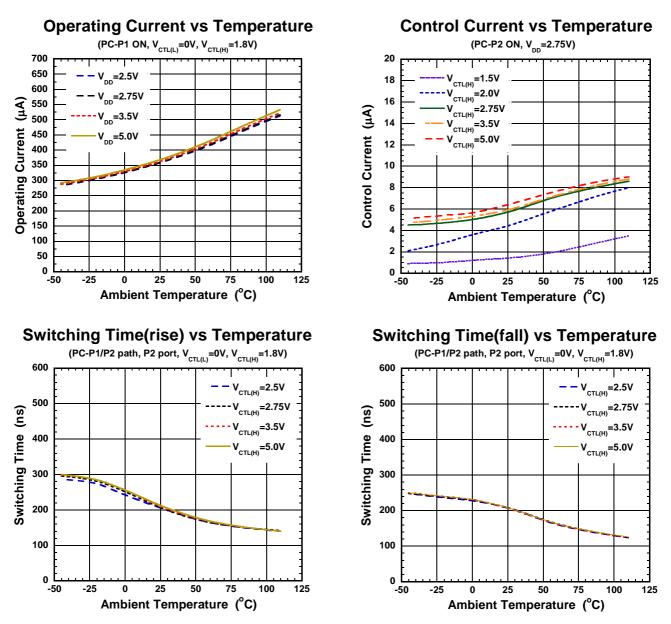
Time (1µs/div)

New Japan Radio Co.,Ltd.

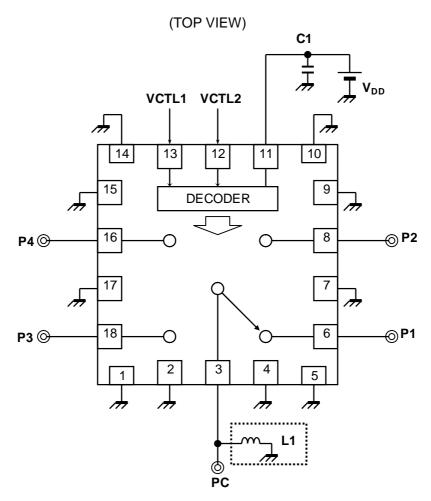


New Japan Radio Co., Ltd.





## ■ APPLICATION CIRCUIT



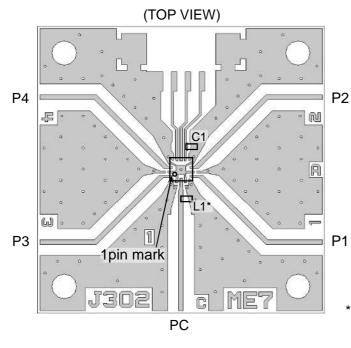
Note:

- [1] No DC blocking capacitors are required on all RF ports, unless DC is biased externally.
- [2] The inductor L1 is optional in order to achieve enhancing ESD protection level. L1 is also recommended in order to keep the DC bias level of each RF port at ground level tightly.

### PARTS LIST

No.	Parameters	Note
C1	1000pF	MURATA (GRM15)
L1	68nH	TAIYO-YUDEN (HK1005)

## PCB LAYOUT

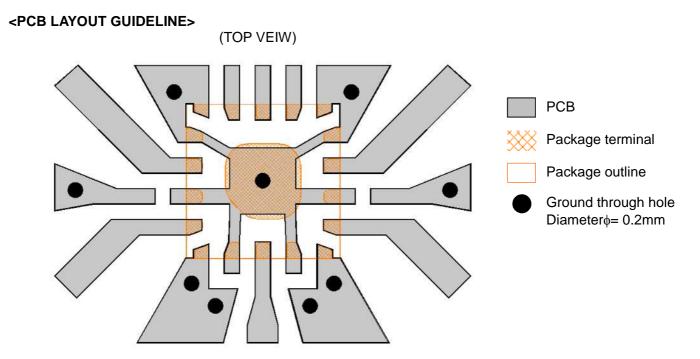


FR-4, t=0.2mm
1005
0.4mm
26x26mm <sup>2</sup>

Losses of PCB and connectors, Ta=+25 °C

Frequency (GHz)	Loss (dB)
0.7	0.16
2.0	0.43
2.7	0.56
3.5	0.68
5.85	1.02

\* L1 is optional.



## ■ PRECAUTIONS

- [1] No DC block capacitors are required for RF ports unless DC is biased externally. When other device biased at certain voltage is connected to the NJG1809ME7, a DC block capacitor is required between the device and this switch IC. This is because the each RF port of this switch is biased at ground level.
- [2] For avoiding the degradation of RF performance, the bypass capacitor (C1) should be placed as close as possible to VDD terminal.
- [3] For good RF performance, all GND terminals are must be connected to PCB ground plane of substrate, and through holes for GND should be placed near the IC.
- [4] Please connect Exposed PAD to PCB ground plane of substrate, and through holes for ground should be placed under the IC.

## ■ RECOMMENDED FOOTPRINT PATTERN (EQFN18-E7 PACKAGE REFERENCE)

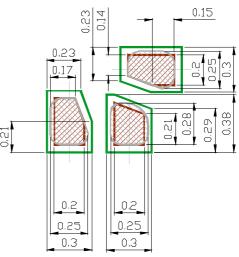
💹 : Land

: Resist (Open area)

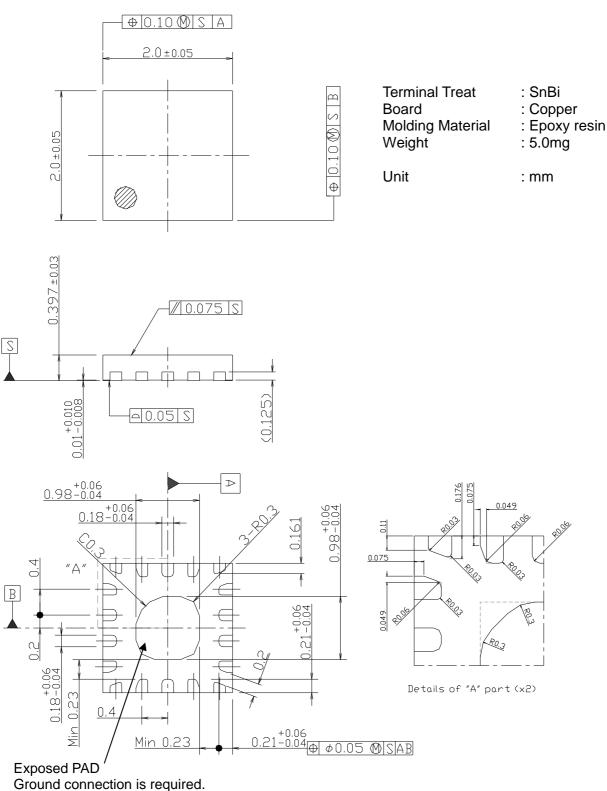
- S : Mask (Open area) \*Metal mask thickness: 100μm
- PKG: 2.0x2.0mm<sup>2</sup> Pin pitch: 0.4mm
- 2.3 2.2 2.0(PKG Line) 0.96 0.86 0.41 0.76 0.31 0.3 0.25 0.2 0.23 0.17 2.0(PKG Line) 0.76 0.96 0,86 0 N N N 1 Ú 0.4 0.21 1 0.8 0.41 0.31 Α 1.6 0.0 0<sup>.05</sup>

Unit: mm





## ■ PACKAGE OUTLINE (EQFN18-E7)



#### Cautions on using this product

- This product contains Gallium-Arsenide (GaAs) which is a harmful material.
- Do NOT eat or put into mouth.
- Do NOT dispose in fire or break up this product.
- Do NOT chemically make gas or powder with this product.
- To waste this product, please obey the relating law of your country.

This product may be damaged with electric static discharge (ESD) or spike voltage. Please handle with care to avoid these damages.

[CAUTION]

The specifications on this databook are only given for information, without any guarantee as regards either mistakes or omissions. The application circuits in this databook are described only to show representative usages of the product and not intended for the guarantee or permission of any right including the industrial rights.

New Japan Radio Co., Ltd.

## **Mouser Electronics**

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Nisshinbo Micro Devices: NJG1809ME7-TE1